

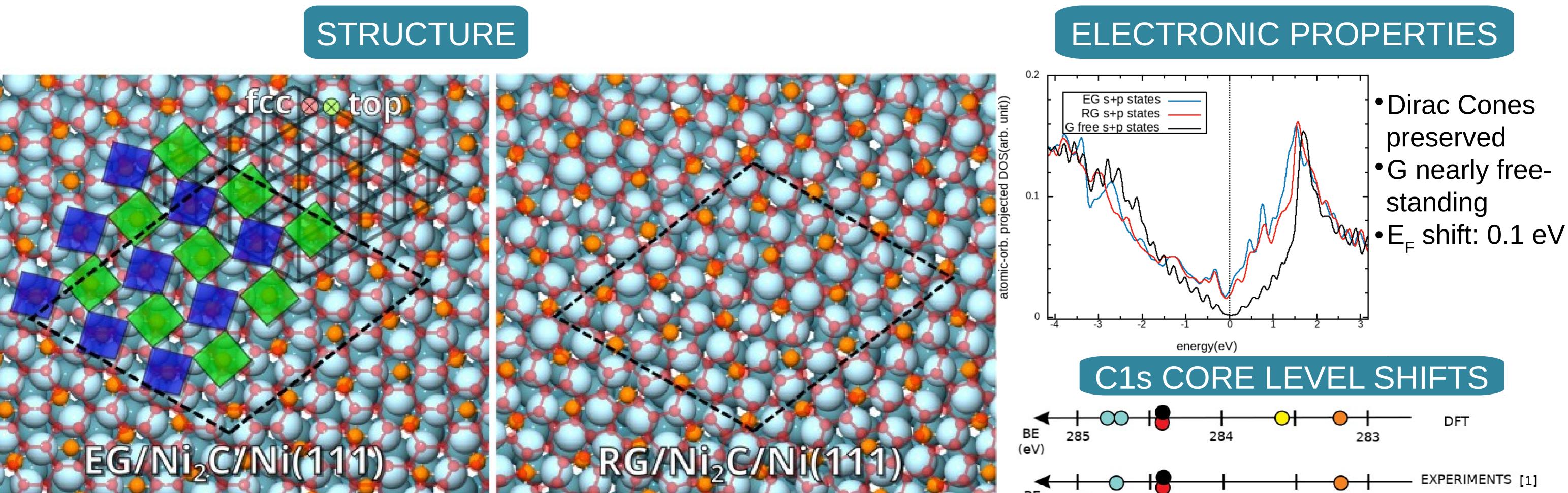
Ni₂C formation at the graphene/Ni(111) interface: a first-principles investigation

Simone Del Puppo¹, Srdjan Stavrić ^{1,2}, Željko Šljivančanin ², Maria Peressi ¹

¹Department of Physics, University of Trieste, via Valerio 2, I-34127 Trieste, Italy ²Vinča Institute of Nuclear Sciences, University of Belgrade, P. O. Box 522, RS-11001, Republic of Serbia

ABSTRAC1

The peculiar graphene(G) properties are very sensitive to its coupling with the substrate. In case of G grown on Ni(111) surface, this is strongly affected by the formation of an intercalated carbide (Ni₂C) layer, which, remarkably, occurs only under rotated graphene (RG) and not under epitaxial graphene (EG) domains [1,2]. We performed first principles simulations based on density functional theory to explain the preferential surface segregation of the Ni-dissolved C atoms under RG domains [3]. Furthermore, a complete description of the electronic properties of G with and without carbide, in RG and EG domains is obtained. Finally, we obtained the specific C1s core level shifts that are the fingerprints of different G/Ni₂C/Ni(111) configurations in good agreement with the experimental results.

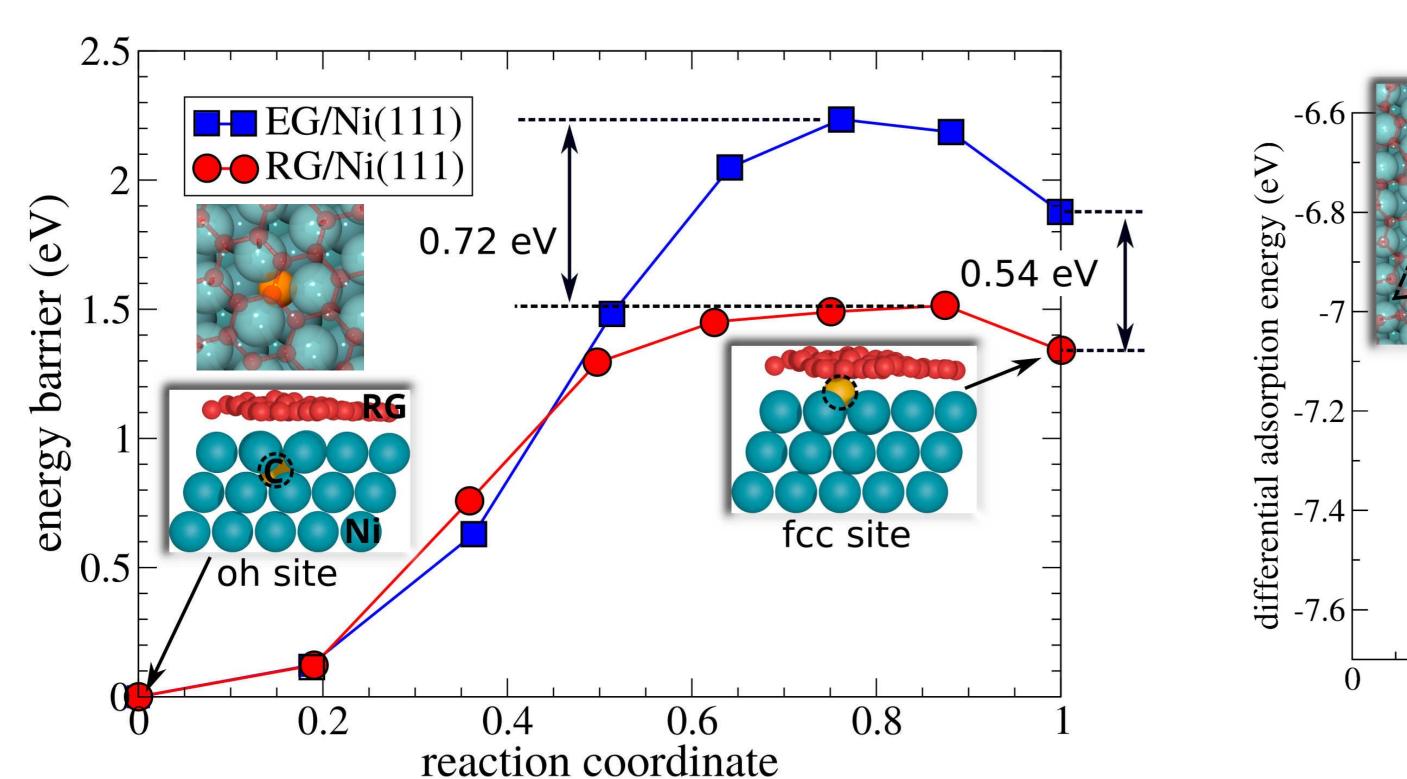


• Ni₂C is stable under both EG and RG • simulation cell: 6 x($\sqrt{43}$ R 7°.6) • matching three different lattices (and • Ni, C detaches both EG and RG from Ni G with two different orientations)

TOWARDS CARBIDE FORMATION



284



INCREASING THE CONCENTRATION OF SUBSURFACE C

- **EG/Ni**(111) **• R**G/Ni(111) 0.2 0.3 0.1 0.4 concentration (C atoms / Ni atoms per layer)
- C added one-by-one on oh sites

283

- concentration < 0.35: similar chemical potential in EG and RG
- concentration > 0.35: opposite behaviour, under EG further segregation is more difficult

SURFACE SEGREGATION OF NI-DISSOLVED C

- subsurface oh sites are the most stable both in RG and EG for dissolved C
- Surface segregation is an activated process (higher energy barrier under EG)

CONCLUSIONS

- EG and RG detached by Ni₂C from the surface (~ free-standing features)
- Ni-dissolved C atoms prefer subsurface octahedral sites
- Carbide formation favored only under RG for thermodynamics and kinetics arguments

CONTACT PERSON

Simone Del Puppo SIMONE.DELPUPPO@phd.units.it

REFERENCES

[1] C. Africh et al., Scientific Reports 6 (2016) 19734. [2] L. L. Patera et al., ACS Nano 7 (2013) 7901. [3] S. Stavrić et al., to be submitted



Project funded by a grant from the Italian Ministry of Foreign Affairs and International Cooperation.

